Nguyen over sheet with the code (S) CLOSED in this appropriate communication application is subject to (308.) 03.	olication. If not include will be mailed in due	ed course. THIS
. Nguyen over sheet with the constant of the	Art Unit 2818 orrespondence addre olication. If not include will be mailed in due of	ed course. THIS
over sheet with the constant of the constant o	2818 orrespondence addre	ed course. THIS
over sheet with the constant of the constant o	orrespondence addre dication. If not include will be mailed in due o	ed course. THIS
tS) CLOSED in this appropriate communication application is subject to 308.	olication. If not include will be mailed in due	ed course. THIS
c. § 119(a)-(d) or (f).		
C. § 119(a)-(d) or (f).		
c. § 119(a)-(d) or (f).		
be written on the drawin ording to 37 CFR 1.121(c	complying with the requestion is deficient. 948) attached ffice action of logs in the front (not the fi). hust be submitted. Note the five the five submitted.	juirements OTICE OF
☐ Interview Summary Paper No./Mail Date ☐ Examiner's Amendm	(PTO-413), e nent/Comment	·
	TAN'T NGUVE	1
	be written on the drawing to 37 CFR 1.121(c) GICAL MATERIAL IN POSIT OF BIOLOGICAL MATERIAL IN PAPER No./Mail Date Examiner's Amendmate	be written on the drawings in the front (not the ording to 37 CFR 1.121(d). GICAL MATERIAL must be submitted. No POSIT OF BIOLOGICAL MATERIAL. Notice of Informal Patent Application (PTO Interview Summary (PTO-413), Paper No./Mail Date Examiner's Amendment/Comment Examiner's Statement of Reasons for Allogory. Other TAN T. NGUYEN

PRIMARY EXAMINER GROUP 2800 The Information Disclosure Statements submitted by Applicants on January 13,
 and February 27, 2004 have been received and fully considered.

Page 2

2. The following is an examiner's statement of reasons for allowance:

The closest prior art to the present invention is Smith et al. (U.S. Patent No. 6,625,055).

Smith et al. disclosed a two terminal memory cell having its resistance values

correspond to multiple logical bits. Smith et al. failed to show or suggest the memory

cells are non-linear resistive memory element.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Tan T. Nguyen whose telephone number is (571) 272-1789. The examiner can normally be reached on Monday to Friday from 07:00 M to 03:00 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David C. Nelms, can be reached at (571) 272-1787. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only.

Art Unit: 2818

For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic

Business Center (EBC) at 866-217-9197 (toll-free).

Tan T. Nguyen Primary Examiner Art Unit 2818 October 21, 2004